LM301A, LM201A, LM201AV

Non Compensated Single Operational Amplifiers

A general purpose operational amplifier that allows the user to choose the compensation capacitor best suited to his needs. With proper compensation, summing amplifier slew rates to 10 V/μs can be obtained.

Features

- Low Input Offset Current: 20 nA Maximum Over Temperature Range
- External Frequency Compensation for Flexibility
- Class AB Output Provides Excellent Linearity
- Output Short Circuit Protection
- Guaranteed Drift Characteristics
- Pb−Free Packages are Available

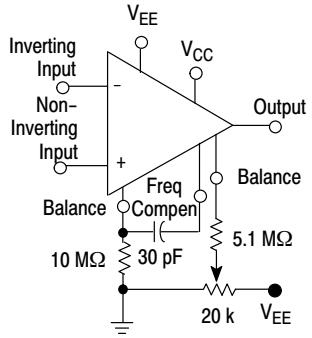
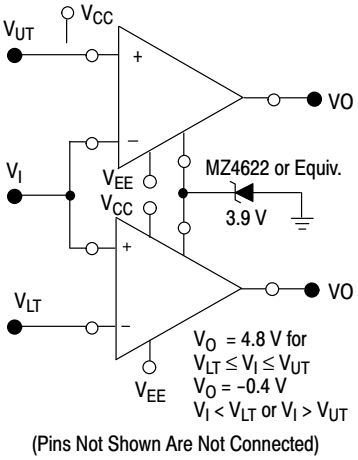


Figure 1. Standard Compensation and Offset Balancing Circuit



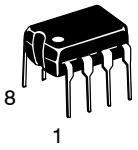
(Pins Not Shown Are Not Connected)

Figure 2. Double−Ended Limit Detector

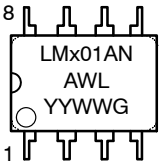
ON Semiconductor®

http://onsemi.com

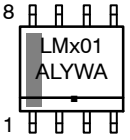
MARKING DIAGRAMS



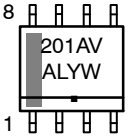
PDIP−8
N SUFFIX
CASE 626



SOIC−8
D SUFFIX
CASE 751

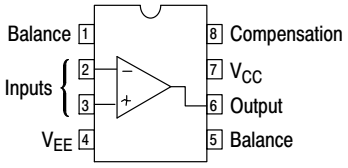


LM201AVDR2G



x	= 2 or 3
A	= Assembly Location
WL, L	= Wafer Lot
YY, Y	= Year
WW, W	= Work Week
G	= Pb−Free Package
▪	= Pb−Free Package

PIN CONNECTIONS



(Top View)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

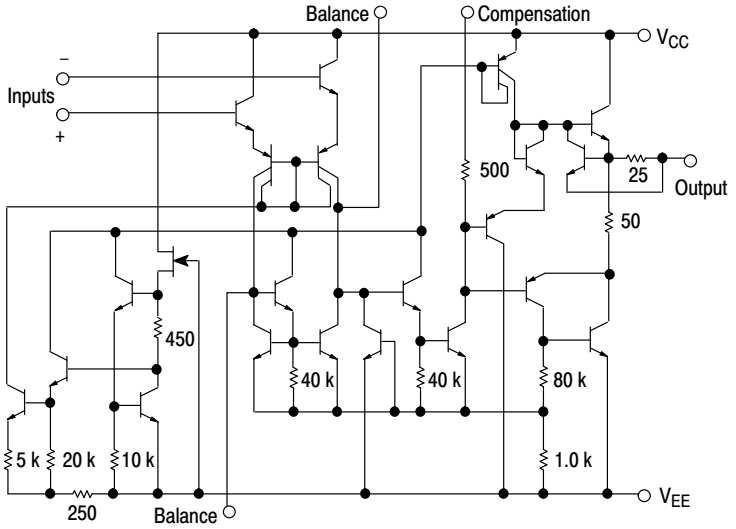


Figure 3. Representative Circuit Schematic

ORDERING INFORMATION

Device	Package	Shipping†
LM301ADG	SOIC−8 (Pb−Free)	98 Units/Rail
LM301ADR2G	SOIC−8 (Pb−Free)	2500 Tape & Reel
LM301AN	PDIP−8	50 Units/Rail
LM301ANG	PDIP−8 (Pb−Free)	50 Units/Rail
LM201ADG	SOIC−8 (Pb−Free)	98 Units/Rail
LM201ADR2G	SOIC−8 (Pb−Free)	2500 Tape & Reel
LM201AN	PDIP−8	50 Units/Rail
LM201ANG	PDIP−8 (Pb−Free)	50 Units/Rail
LM201AVDR2G	SOIC−8 (Pb−Free)	2500 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Rating	Symbol	Value			Unit
		LM201A	LM201AV	LM301A	
Power Supply Voltage	V_{CC}, V_{EE}	±22	±22	±18	Vdc
Input Differential Voltage	V_{ID}	±30			V
Input Common Mode Range (Note 1)	V_{ICR}	±15			V
Output Short Circuit Duration	t_{SC}	Continuous			
Power Dissipation (Package Limitation)	P_D				
Plastic Dual−In−Line Package		625	625	625	mW
Derate above T_A = +25°C		5.0	5.0	5.0	mW/°C
Operating Ambient Temperature Range	T_A	−25 to +85	−40 to +105	0 to +70	°C
Storage Temperature Range	T_{stg}	−65 to +150			°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ELECTRICAL CHARACTERISTICS (T_A = +25°C, unless otherwise noted.) Unless otherwise specified, these specifications apply for supply voltages from ±5.0 V to ±20 V for the LM201A and LM201AV, and from ±5.0 V to ±15 V for the LM301A.

Characteristic	Symbol	LM201A / LM201AV			LM301A			Unit
		Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage (R_S ≤ 50 kΩ)	V_{IO}	–	0.7	2.0	–	2.0	7.5	mV
Input Offset Current	I_{IO}	–	1.5	10	–	3.0	50	nA
Input Bias Current	I_{IB}	–	30	75	–	70	250	nA
Input Resistance	r_i	1.5	4.0	–	0.5	2.0	–	MΩ
Supply Current	I_{CC},I_{EE}							mA
V_{CC}/V_{EE} = ±20 V		–	1.8	3.0	–	–	–	
V_{CC}/V_{EE} = ±15 V		–	–	–	–	1.8	3.0	
Large Signal Voltage Gain (V_{CC}/V_{EE} = ±15 V, V_O = ±10 V, R_L > 2.0 kΩ)	A_V	50	160	–	25	160	–	V/mV
The following specifications apply over the operating temperature range.								
Input Offset Voltage (R_S ≤ 50 kΩ)	V_{IO}	–	–	3.0	–	–	10	mV
Input Offset Current	I_{IO}	–	–	20	–	–	70	nA
Avg Temperature Coefficient of Input Offset Voltage (Note 2) T_A(min) ≤ T_A ≤ T_A (max)	$\Delta V_{IO}/\Delta T$	–	3.0	15	–	6.0	30	μV/°C
Avg Temperature Coefficient of Input Offset Current (Note 2)	$\Delta I_{IO}/\Delta T$							nA/°C
+25°C ≤ T_A ≤ T_A (max)		–	0.01	0.1	–	0.01	0.3	
T_A(min) ≤ T_A ≤ 25°C		–	0.02	0.2	–	0.02	0.6	
Input Bias Current	I_{IB}	–	–	100	–	–	300	nA
Large Signal Voltage Gain (V_{CC}/V_{EE} = ±15 V, V_O = ±10V, R_L > 2.0 kΩ)	A_{VOL}	25	–	–	15	–	–	V/mV
Input Voltage Range	V_{ICR}							V
V_{CC}/V_{EE} = ±20 V		−15	–	+15	–	–	–	
V_{CC}/V_{EE} = ±15 V		–	–	–	−12	–	+12	
Common Mode Rejection (R_S ≤ 50 kΩ)	CMR	80	96	–	70	90	–	dB
Supply Voltage Rejection (R_S ≤ 50 kΩ)	PSR	80	96	–	70	96	–	dB
Output Voltage Swing	V_O	±12	±14	–	±12	±14	–	V
(V_{CC}/V_{EE} = ±15 V, R_L = ±10 kΩ, R_L > 2.0 kΩ)		±10	±13	–	±10	±13	–	
Supply Currents (T_A = T_A(max), V_{CC}/V_{EE} = ±20 V)	I_{CC},I_{EE}	–	1.2	2.5	–	–	–	mA

1. For supply voltages less than ±15 V, the absolute maximum input voltage is equal to the supply voltage.
2. Guaranteed by design.

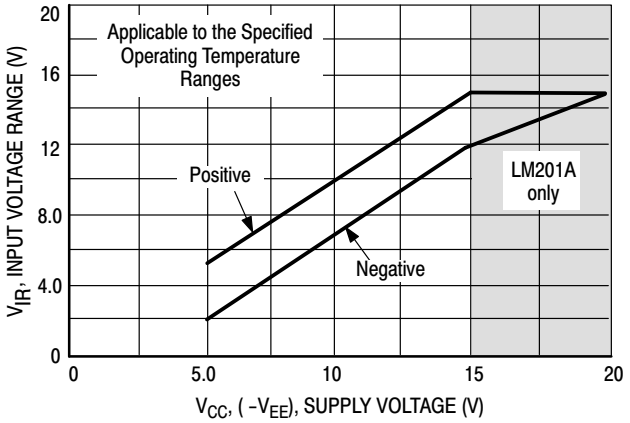


Figure 4. Minimum Input Voltage Range

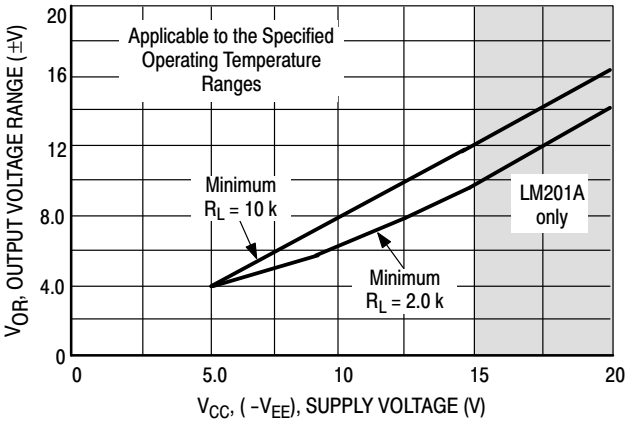


Figure 5. Minimum Output Voltage Swing

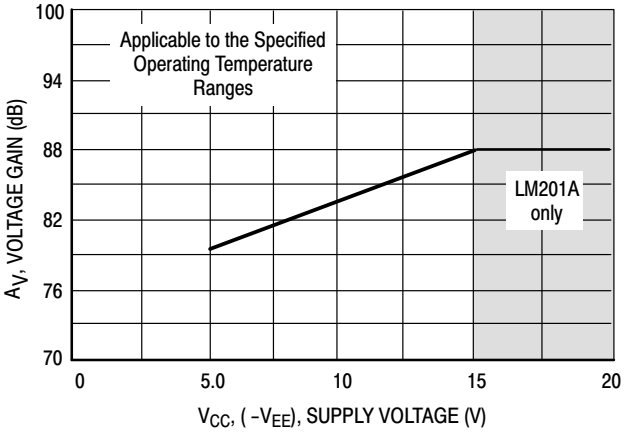


Figure 6. Minimum Voltage Gain

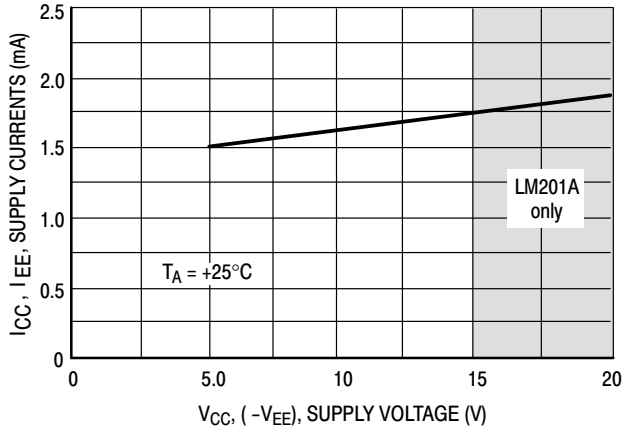


Figure 7. Typical Supply Currents

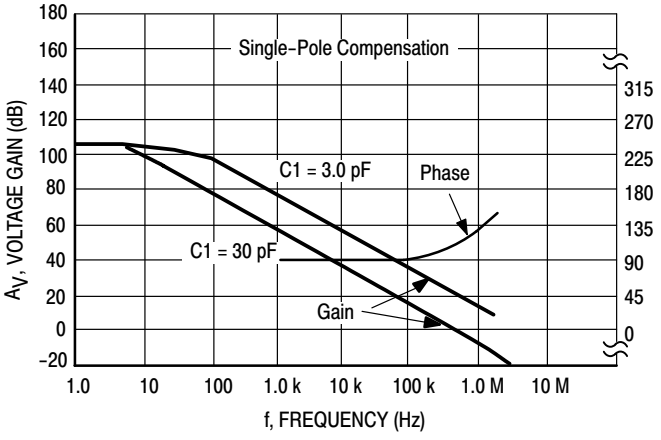


Figure 8. Open Loop Frequency Response

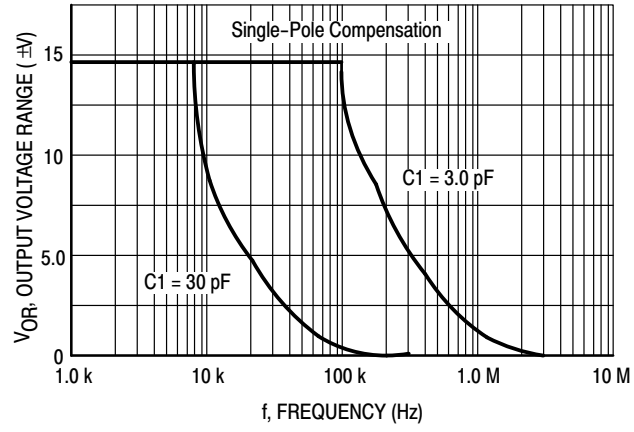


Figure 9. Large Signal Frequency Response

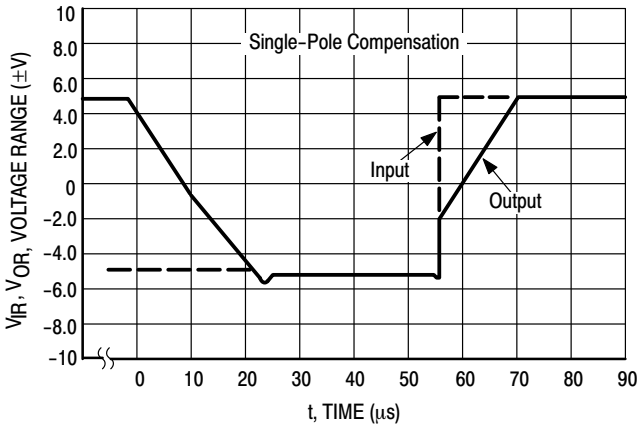


Figure 10. Voltage Follower Pulse Response

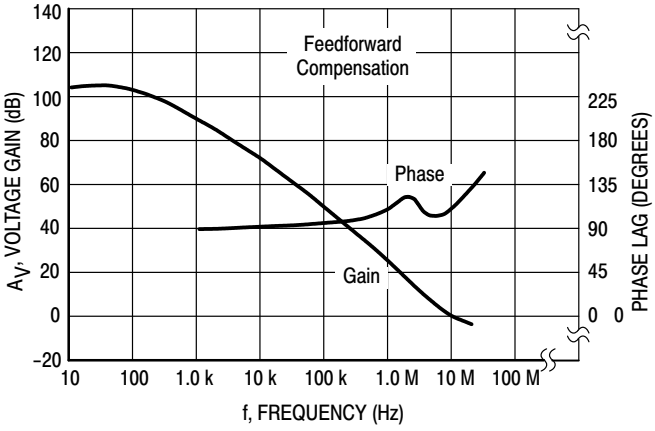


Figure 11. Open Loop Frequency Response

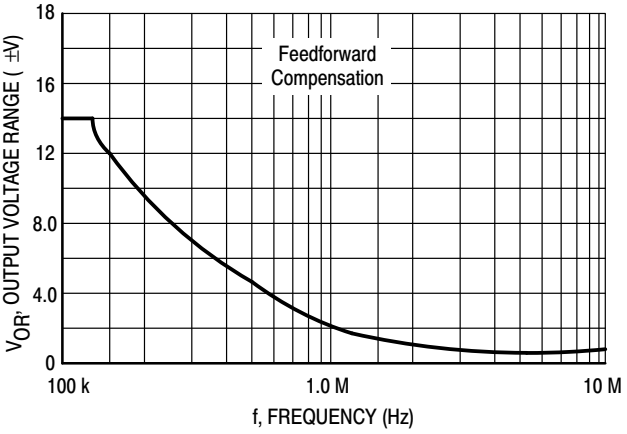


Figure 12. Large Signal Frequency Response

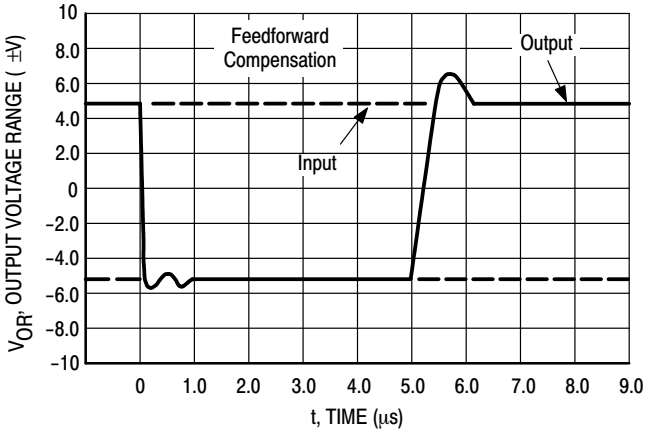


Figure 13. Inverter Pulse Response

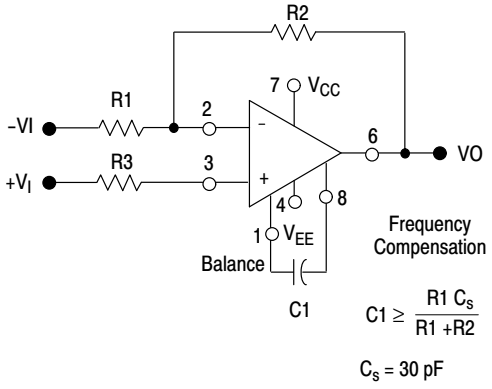


Figure 14. Single−Pole Compensation

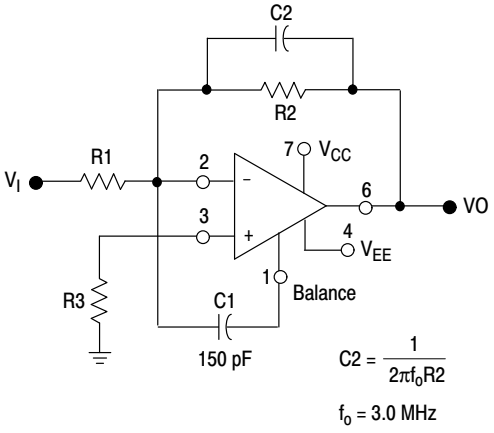
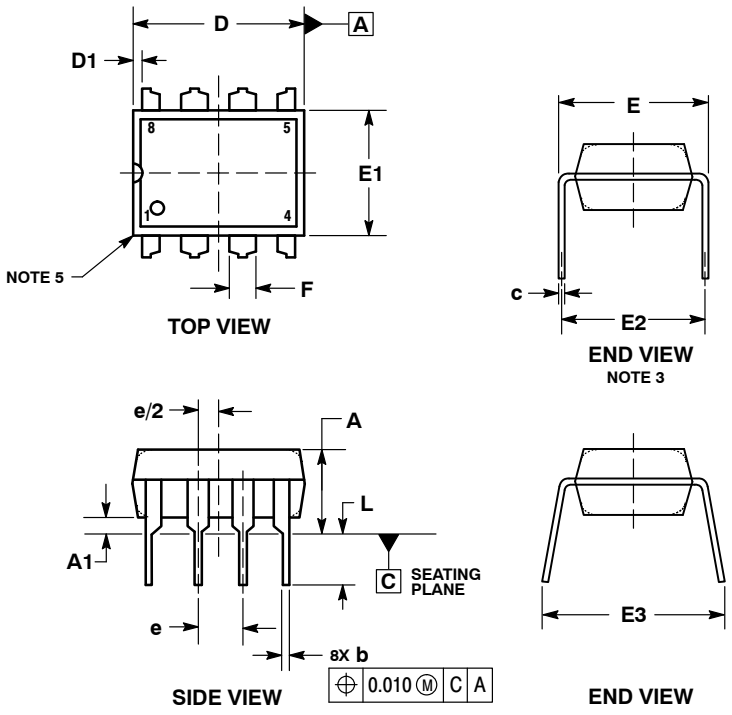


Figure 15. Feedforward Compensation

PACKAGE DIMENSIONS

8 LEAD PDIP
CASE 626−05
ISSUE M

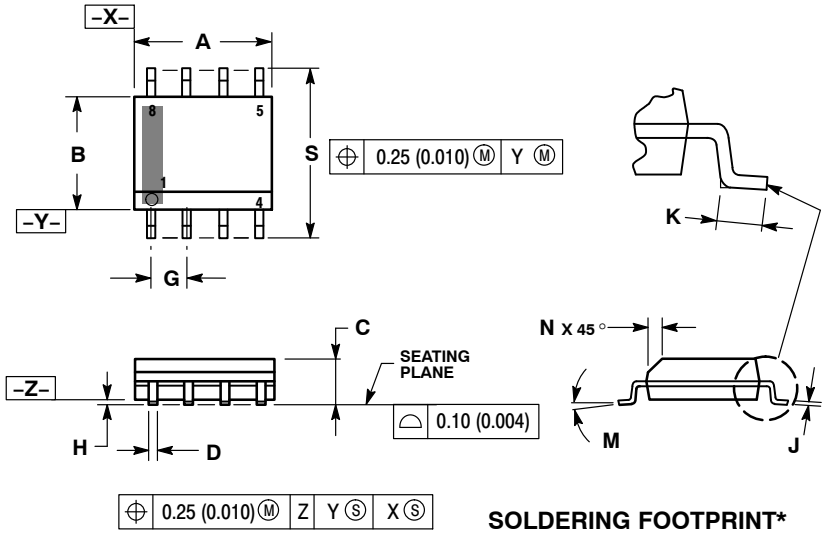


NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSION E IS MEASURED WITH THE LEADS RESTRAINED PARALLEL AT WIDTH E2.
4. DIMENSION E1 DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

	INCHES			MILLIMETERS		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
A	----	----	0.210	----	----	5.33
A1	0.015	----	----	0.38	----	----
b	0.014	0.018	0.022	0.35	0.46	0.56
C	0.008	0.010	0.014	0.20	0.25	0.36
D	0.355	0.365	0.400	9.02	9.27	10.02
D1	0.005	----	----	0.13	----	----
E	0.300	0.310	0.325	7.62	7.87	8.26
E1	0.240	0.250	0.280	6.10	6.35	7.11
E2	0.300 BSC			7.62 BSC		
E3	----	----	0.430	----	----	10.92
e	0.100 BSC			2.54 BSC		
L	0.115	0.130	0.150	2.92	3.30	3.81

PACKAGE DIMENSIONS

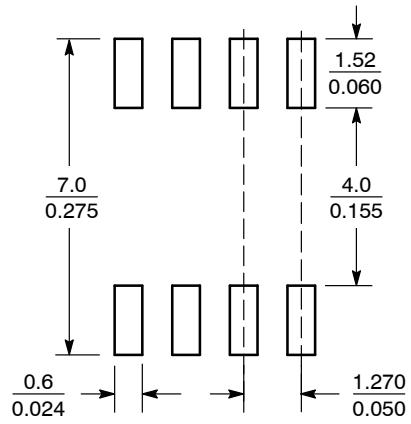
SOIC−8 NB
CASE 751−07
ISSUE AK



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751−01 THRU 751−06 ARE OBSOLETE. NEW STANDARD IS 751−07.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

SOLDERING FOOTPRINT*



SCALE 6:1 $\left(\frac{\text{mm}}{\text{inches}}\right)$

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303−675−2175 or 800−344−3860 Toll Free USA/Canada
Fax: 303−675−2176 or 800−344−3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800−282−9855 Toll Free USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81−3−5817−1050

ON Semiconductor Website: **www.onsemi.com**

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001
Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

http://moschip.ru/get-element

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:
moschip.ru
moschip.ru_4
moschip.ru_6
moschip.ru_9